L Number	Hits	Search Text	DB	Time stamp
1	454	257/173.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/28 12:40
2	106	257/174.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/28 12:40
-	495	surrounded adj (source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/28 12:22
-	2	island adj surrounded adj (source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 06:51
-	0	island adj formed adj within adj (source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 06:55
-	2	island and 5721439.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:31
-	1540	mosfet and (esd or (electrostatic adj discharge))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:33
-	0	mosfet and (esd or (electrostatic adj discharge)) and (breakdown adj enhanced adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:52
-	0	mosfet and (esd or (electrostatic adj discharge)) and (breakdown adj enhancement)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:34
-	2	mosfet and (esd or (electrostatic adj discharge)) and (breakdown adj enhanced)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:35
-	2	mosfet and (esd or (electrostatic adj discharge)) and (breakdown near enhanced)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:35
-	19	mosfet and (esd or (electrostatic adj discharge)) and (breakdown near enhance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:39
-	38	mosfet and (esd or (electrostatic adj discharge)) and (breakdown near increase)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:46
-	12	mosfet and (esd or (electrostatic adj discharge)) and (breakdown near improve)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:47

-		4	mosfet and (esd or (electrostatic adj discharge)) and (breakdown adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:51
-		0	mosfet and (esd or (electrostatic adj discharge)) and (break adj down adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:52
-		2	(breakdown adj enhanced adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:55
-		2	(breakdown adj enhancement adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:54
-		0	(breakdown adj enhancing adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:54
-		0	(breakdown adj improving adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:56
-		2	(breakdown adj improvement adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:58
-		1	(breakdown adj increased adj (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 07:58
-		66	(layer or film) adj increases adj breakdown	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:04
-		56	(layer or film) adj improves adj breakdown	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:08
-		7	(layer or film) adj enhances adj breakdown	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:13
-		2	6514839.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:15
-		2	20020076876.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:16
-		2	6008080.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:17

-	2	6268256.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:18
-	2	6100141.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:32
-	9	enclosed adj source adj drain adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:35
-	1	encircled adj source adj drain adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:39
-	0	engulfed adj source adj drain adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:40
-	13	bounded adj source adj drain adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:43
-	3	bordered adj source adj drain adj region	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 08:43